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<td>Xiang, HF; Xu, ZX; Roy, VAL; Che, CM; Lai, PT; Zeng, PJ; Niu, FF; Liu, YW; Tang, WQ; He, CJ; Niu, HB</td>
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<tr>
<td><strong>Citation</strong></td>
<td>Applied Physics Letters, 2008, v. 92 n. 7</td>
</tr>
<tr>
<td><strong>Issued Date</strong></td>
<td>2008</td>
</tr>
<tr>
<td><strong>URL</strong></td>
<td><a href="http://hdl.handle.net/10722/57312">http://hdl.handle.net/10722/57312</a></td>
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Star-configured carbazole as an efficient near-ultraviolet emitter and hole-transporting material for organic light-emitting devices

Hai-Feng Xiang,1 Zong-Xiang Xu,1 V. A. L. Roy,1 Chi-Ming Che,1,a P. T. Lai,2 Peng-Ju Zeng,3,b Fang-Fang Niu,1 Ya-Wei Liu,3 Wei-Qun Tang,3 Cai-Jie He,3 and Han-Ben Niu3

1Department of Chemistry and HKU-CAS Joint Laboratory on New Materials, The University of Hong Kong, Pokfulam Road, Hong Kong SAR, People’s Republic of China
2Department of Electrical and Electronic Engineering, The University of Hong Kong, Pokfulam Road, Hong Kong SAR, People’s Republic of China
3Institute of Optoelectronics, College of Optoelectronics Engineering, Shenzhen University, Shenzhen, People’s Republic of China

(Received 30 November 2007; accepted 17 January 2008; published online 20 February 2008)

A novel organic material, 9-methyl-1,3,6,8-tetraphenyl-carbazole (MTPC-Me), for use in organic electroluminescent devices has been developed. This star-configured carbazole gives a strong near-ultraviolet (n-UV) emission (λmax=389 nm) with a high emission quantum efficiency of 47% and a narrow full width half maximum of 40 nm. Two types of high-performance organic light-emitting devices were obtained using MTPC-Me as a n-UV emitter and hole-transporting material with maximum external quantum efficiency, brightness, and turn-on voltage of 1.2%, 1040 cd/m², and 3.5 V for the former and 1.1%, 18 000 cd/m², and 2.4 V for the latter, respectively. © 2008 American Institute of Physics. [DOI: 10.1063/1.2841063]

The performance of red-to-blue organic light-emitting devices (OLEDs) has improved dramatically over the past decade.1–5 However, extending OLED emission into the ultraviolet (UV) or near-ultraviolet (n-UV) wavelength is still challenging, despite the useful applications of n-UV OLEDs as an excitation light source for red-to-blue or white luminescence conversion and in high-density information storage devices. In addition, UV or n-UV emitters are widely used as a host material for triplet dopant emitters in phosphorescent OLEDs.6,7 To date, only several n-UV emitters, such as 4,4′-N,N′-dicarbazole-biphenyl (CBP),7 N,N′-diphenyl-N,N′-bis(3-methylphenyl)(1,10-biphenyl)-4,4′-diamine (TPD),8,9 and bi(9,9-diaryl-fluorene),10 have been proven to be effective UV or n-UV emitters for OLEDs.

Functionalized carbazoles have played an important role in OLEDs as a host material11,12 and hole-transporting material (HTM).13,14 Here, we report efficient n-UV emission with narrow full width half maximum (FWHM) from a novel 1,3,6,8-substituted carbazole derivative, 9-methyl-1,3,6,8-tetraphenyl-carbazole (MTPC-Me), the structure of which is shown in Fig. 1. Two types of high-performance OLEDs have been fabricated by using this star-configured MTPC-Me carbazole as a n-UV emitter and HTM.

The preparation method of MTPC-Me will be described elsewhere. The characteristic data of this compound are as follows: mp, 236.2 °C; MS-El(m/e), 485 (M+, 100.00%), 486 (30%), 243 (15%); elemental analyses: calculated percentage for C32H27N: C 91.51%, H 5.60%, N 2.88%; found: C 91.20%, H 5.56%, N 2.68%; 1H NMR(CDCl3,500 Hz) δ 2.94(3H,s), 7.38–7.42(4H,m), 7.47–7.52(8H,q), 7.60–7.65(2H,m), 7.80–7.81(4H,t), 8.42–8.42(2H,d). Three different types of OLEDs were fabricated:

- **device A**: indium-tin oxide (ITO)/MTPC-Me (50 nm)/Alq3 (50 nm)/LiF (0.5 nm)/Al (100 nm),
- **device B**: ITO/NPB (50 nm)/Alq3 (50 nm)/LiF (0.5 nm)/Al (100 nm), and
- **device C**: ITO/CuPc (30 nm)/MTPC-Me (30 nm)/BCP (10 nm)/Alq3 (30 nm)/LiF (0.5 nm)/Al (100 nm), where ITO glass is transparent anode; copper(II) phthalocyanine (CuPc) is hole-injecting material; N,N′-bis(naphthyl)-N,N′-diphenyl-1,1′-biphenyl-4,4′-diamine (NPB) is HTM; 2,9-dimethyl-4,7-diphenyl-1,10-phenanthroline (BCP) is hole-blocking material (HBM); and tris-(8-hydroxyquinolato)aluminum(III) (Alq3) is electron-transporting material (ETM) or emitting material (EM). In this work, all OLEDs were prepared on patterned ITO glass with a sheet resistance of 20 Ω/□. All layers of the OLEDs were grown by thermal evaporation under a vacuum of 1 × 10⁻⁶ Torr. The device performance was examined using Photosresearch PR-650 and Keithley 2400 source meter. All chemicals were sublimed before use.

We have not been able to obtain crystals of MTPC-Me with quality good enough for single crystal x-ray structure determination. Nevertheless, we have obtained crystals of its analog 9-ethyl-1,3,6,8-tetraphenyl-carbazole (MTPC-Et) and determined its crystal structure. As depicted in Fig. 2, due to the four phenyl groups, MTPC-Et is sterically bulky with a...
star-configured structure and this is essential for this kind of compounds to acquire enough morphological thin-film stability and thermal stability. The decomposition temperature and glass transition ($T_g$) of MTPC-Me was found to be 351 and 220 °C, respectively. The energy levels calculated using cyclic voltammetric data of this compound are shown in Fig. 1. The energy level of the highest occupied molecular orbital (HOMO, $-5.2$ eV) and lowest unoccupied molecular orbital (LUMO, $-2.0$ eV) of MTPC-Me are comparable to those of NPB (HOMO, $-5.2$ eV; LUMO $-2.2$ eV). With a large band gap of $3.2$ eV, MTPC-Me emits a strong n-UV light ($\lambda_{\text{max}}=389$ nm, decay lifetime=5.3 ns) with a high photoluminescent (PL) quantum efficiency of $47\%$ (quinine in 0.05 mol/l sulfate as standard) and FWHM of 40 nm in CH$_2$Cl$_2$ solution, as depicted in Fig. 3. The PL emission of MTPC-Me film ($\lambda_{\text{max}}=395$ nm) shows a little redshift from that recorded in CH$_2$Cl$_2$ solution, presumably this could be attributed to molecular aggregation in the solid state. On the basis of its good thermal and morphological stability, appropriate energy levels, strong n-UV emission, and hole-transporting nature of carbazole-containing compound, MTPC-Me is expected to be a good HTM and EM.

A double-layer device A with MTPC-Me as HTM and Alq$_3$ as EM and ETM was fabricated. For comparison, a standard device B with a similar structure but using NPB as HTM was also fabricated. Similar to the NPB-based device B, the MTPC-Me-based device A gave a green emission with a peak $\lambda_{\text{max}}$ at 530 nm, a characteristic of the emission of Alq$_3$ (Fig. 4), indicating that charge recombination is localized in the Alq$_3$ layer and MTPC-Me acted primarily as a HTM without causing exciton formation at the interface with Alq$_3$. This should be attributed to the appropriate HOMO

![Chemical structure and crystal structure of MTPC-Et.](image1)

![Absorption (dash line, in CH$_2$Cl$_2$) and PL emission (dot line, in CH$_2$Cl$_2$; solid line, thin film) spectra of MTPC-Me.](image2)

![EL spectrum of device A (top) and external quantum efficiency, current density, and brightness curves (inset) of devices A and B (bottom) vs the applied voltage.](image3)
the current density and luminance of the MTPC-Me-based performance of devices A and B are shown in Fig. 4. Both the maximum 1.2%, 1040 cd/m² and brightness of 3.3 cd/m², are comparable to related values found for NPB-based standard devices. 

In device C, a 10-nm-thick BCP film was inserted between MTPC-Me and Alq3 to prevent leaking excitons into the Alq3 layer. Similarly, the appropriate LUMO level of MTPC-Me (a bit higher than that of NPB) blocks electron injection from Alq3 to itself. 

The maximum external quantum efficiency (ηext), luminous efficiency (ηl), brightness, and turn-on voltage (Von) of the MTPC-Me-based device A are 1.1%, 3.3 cd/A, 18,000 cd/m², and 2.4 V, respectively, comparable to the related values found for NPB-based standard device B (maximum ηext, ηl, brightness, and Von of 1.3%, 4.0 cd/A, and 25,000 cd/m², and 2.3 V, respectively). The hole mobility of MTPC-Me determined by time-of-flight measurement is about 1.9 × 10⁻⁴ cm²/V s, which is comparable to the value reported for NPB.

In device C, a 10-nm-thick BCP film was inserted between MTPC-Me and Alq3 to prevent leaking excitons into the Alq3 layer as BCP layer has a high HOMO level compared to Alq3 and would block the passage of holes out of MTPC-Me. Device C gave a pure n-UV EL emission (λmax = 396 nm) with a narrow FWHM of 40 nm, as shown in Fig. 5. The maximum ηext, brightness, and Von of device C are 1.2%, 1040 cd/m², and 3.5 V (Fig. 5), respectively, comparable to that found for CBP (Ref. 7) and TPD-based n-UV OLEDs. Recently, a high-performance n-UV OLEDs with a high ηext up to 3.6%, was reported by using 2,2'-bi-9,9'-spirobifluorene (B2). However, the EL emission from this n-UV OLED extended into visible region (λmax ≈ 425 nm) and its FWHM broadened to ~70 nm. The Von of device C was higher than that of device A or device B, this would be attributed to the LUMO level of MTPC-Me (~2.0 eV) at higher energy level than that of BCP (~2.9 eV), resulting in higher energy barrier for electrons to jump into the MTPC-Me layer. This barrier might be reduced by replacing BCP/Alq3 with a HBM and ETM of (1,3,5-phenylene) tris(1-phenyl-1H-benzimidazole).

In summary, a novel wide-band-gap 1,3,6,8-substituted carbazole derivative with a good thermal stability, a good hole-transporting property, and a stong n-UV emission was prepared and successfully used as an efficient n-UV EM and HTM in OLEDs. Given the fact that the molecular structure and, hence, the electronic properties of MTPC-Me and its derivatives could be varied, the development of high-performance n-UV OLEDs using this kind of compounds is envisaged. The present findings also suggest that MTPC-Me is a potential good host material in electrophosphorescence devices.

This work was supported by the Joint Research Scheme NSFC/RGC (N_HKU 742/04), the University Development Fund (Nanotechnology Research Institute, No. 00600009) of The University of Hong Kong, the Innovation Technology Fund (ITF), Strategic Theme on Nano-Biotechnology, the Strategic Theme on Organic Electronics and RGC of HKSAR (Project Nos. HKU 7158/04E and HKU 200607176144), the Guangdong Province Natural Science Foundation (Grant No. 031805), the Major Program in Key Field of Guangdong Province Government (Grant No. 2003-03), Science and Technology Program of Shenzhen (Grant No. 2006-2007). We acknowledge Clover & Sunc Systems, Ltd., for their support with the fabrication system housed at The University of Hong Kong.

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